

Data sheet acquired from Harris Semiconductor SCHS052B - Revised June 2003

# CMOS Analog Multiplexers/Demultiplexers

High-Voltage Types (20-Volt Rating)

CD4067B - Single 16-Channel

Multiplexer/Demultiplexer

CD4097B -Differential 8-Channel Multiplexer/Demultiplexer

#### ■ CD4067B and CD4097B CMOS

analog multiplexers/demultiplexers\* are digitally controlled analog switches having low ON impedance, low OFF leakage current, and internal address decoding. In addition, the ON resistance is relatively constant over the full input-signal range.

The CD4067B is a 16-channel multiplexer with four binary control inputs, A,B,C,D, and an inhibit input, arranged so that any combination of the inputs selects one switch.

The CD4097B is a differential 8-channel multiplexer having three binary control inputs A, B, C, and an inhibit input. The inputs permit selection of one of eight pairs of switches.

A logic "1" present at the inhibit input turns all channels off.

The CD4067B and CD4097B types are supplied in 24-lead hermetic dual-in-line ceramic packages (F3A suffix), 24-lead dual-in-line plastic packages (E suffix), 24-lead small-outline packages (M, M96, and NSR suffixes), and 24-lead thin shrink small-outline packages (P and PWR suffixes).

When these devices are used as demultiplexers, the channel in/out terminals are the outputs and the common out/in terminals are the inputs.

#### Recommended Operating Conditions at TA = 25°C (Unless Otherwise Specified)

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges. Values shown apply to all types except as

notea.			
Characteristic	Min.	Max.	Units
Supply-Voltage Range (T <sub>A</sub> =Full Package- Temp. Range)	3	18	٧
Multiplexer Switch Input Current Capability	1 -	25	mΑ
Output Load Resistance	100		$\Omega$

#### NOTE:

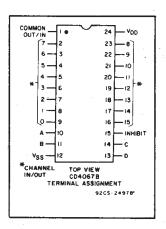
In certain applications, the external load-resistor current may include both V<sub>DD</sub> and signal-line components. To avoid drawing VDD current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 volt (calculated from RON values shown in ELECTRICAL CHARAC-TERISTICS CHART). No VDD current will flow through RL if the switch current flows into terminal 1 on the CD4067; terminals 1 and 17 on the CD4097.

#### Features:

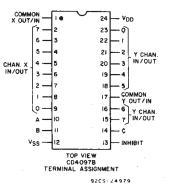
- Low ON resistance: 125  $\Omega$  (typ.) over 15  $V_{p-p}$  signal-input range for  $V_{DD}$  –  $V_{SS}$  = 15 V
- High OFF resistance: channel leakage of ±10 pA (typ.) @ VDD-VSS=10 V
- Matched switch characteristics: RoN=5  $\Omega$  (typ.) for VDD-VSS=15 V
- Very low quiescent power dissipation under all digital-control input and supply conditions: 0.2 μW (typ.) @ VDD-VSS=10 V
- Binary address decoding on chip
- 5-V, 10-V, and 15-V parametric ratings
- 100% tested for quiescent current at 20 V
- Standardized symmetrical output characteristics
- Maximum input current of 1 µA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Meets all requirements of JEDEC Tentative Standard No. 138, "Standard Specifications for Description of 'B' Series CMOS Devices"

#### Applications:

- Analog and digital multiplexing and demultiplexing
- A/D and D/A conversion
- Signal gating



**CD4067B, CD4097B Types** 



OF 16 DECODERS 15 Ö VDD = 24 VSS = 12 Fig. 1 - CD4067 functional diagram.

#### CD4067 TRUTH TABLE

$\overline{}$	_	_			
A	В	С	D	Inh	Selected Channel
х	х	х	Х	1	None
0	0	0	0	0	0
1	0	0	0	.0.	1 .
0	1 ,	0	0	0	2
ī	1	0	0	0	3
0	0	1	0	0	4
1	0	1	0	0	5
0	1	1	0	0	6
1	1	1	0	0	.7
0	0	0	1	0	8
1 1	0	0	1	0	9
0	1	0	1	0	10
1	1	0	1	0	11
0	0	1	1	0	12
1	0	1	1	0	13
0	1	1	1	0	14
1	1	1	1	0	15

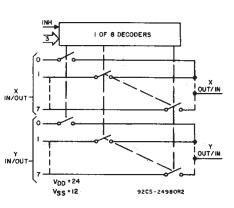


Fig. 2-CD4097 functional diagram.

#### CD4097 TRUTH TABLE

A	В	С	Inh	Selected Channel
х	х	х	1	None
0	0	0	0	0X, 0Y
1	0	0	0	1X, 1Y
0	1	0	0	2X, 2Y
1	1	0	0	3X, 3Y
0	0	1	0	4X, 4Y
1	0	1	0	5X, 5Y
0	1	1	0	6X, 6Y
1	1	1	0	7X, 7Y

#### **ELECTRICAL CHARACTERISTICS**

CHARAC- TERISTIC	,	CONDITIONS		LIMI	TS AT II	NDICAT	ED TEI	MPER/	ATURES	s (°C)	Units
	Vis	v <sub>ss</sub>	$V_{DD}$	-55	-40	+85	+125		+25		]
0100101	(V)	(V)	(V)		<u></u>		L	Min.	Тур.	Max.	<u>l</u>
	יטוטי	V <sub>is</sub> ) AND OUT									
Quiescent			5	5	5	150	150		0.04	5	
Device Cur- rent, IDD			10	10	10	300	.300	_	0.04	10	μΑ
Max.			15	20	20	600	600	- '	0.04	20	-
ON-state Re			20	100	100	3000	3000		0.08	100	
sistance		2 400									
V <sub>SS</sub> ≤		0	5	800	850	1200	1300		470	1050	
Vic≪VDD		0	10	310	330	520	550	_	180	400	- Ω
ron Max.		0	15	200	210	300	320		125	240	
Change in						,			-		
on-state											
Resistance (Between		*					100			1	
Any Two		0	5	_	_	_		1 1	15		
Channels)		0	10		_			_	. 10	<del>                                     </del>	Ω
$\Delta r_{on}$		0	15				-	_ :	5		
OFF Chan-										1	
nel Leak-										1.	
age Cur-											
rent: Any Channel									· ·		
OFF Max.										l	
or		0	18	±1	00*	±100	0*	-	±0.1	±100*	nΑ
All Chan-								İ	ŀ		
nels OFF					Ĭ						
(Common OUT/IN)									ļ		
Max.											
Capacitance:											
Input, C <sub>is</sub>		i		_	-	-	-	-	5	-	
Output,										<u> </u>	1
Cos									İ		
CD4067		-5	5	_		_		l	55	L	pF
CD4097					-	-	1		35		ام ا
Feed-											1
through,				_	_	-	_	-	0.2		
Cios											
Propaga-		R <sub>L</sub> = 200 KΩ	5	_	_	_	-	_	30	60	
tion Delay Time (Sig-	V <sub>DD</sub>	C <sub>L</sub> =50 pF	10	_			_	_	15	30	ns
nal Input		t <sub>r</sub> ,t <sub>f</sub> =20 ns	15	-	_	_			10	20	
to Output		ł J							'`	20	
CONTROL	(ADDI	RESS or INHIB	T) V <sub>C</sub>		·		1,5-	•	Α		
Input Low		R <sub>L</sub> =1 KΩ	5		1.5		<del>:</del>	<u> </u>	<b>—</b> ,	1.5	
Voltage,	}	to Vcc	10		3	<del></del>	-				1
Vill Max.	=VDD	I <sub>‡S</sub> <2 μA							<del>                                     </del>	3	1
1 -	thru	on all OFF	15		4			-		4	V
				1	3.5			125	] :_	1	1
Input High	1 KΩ	Channels	5					3.5		-	1
Input High Voltage, V <sub>IH</sub> Min.	1 K12	Channels	10		7			7	_	-	

<sup>\*</sup> Determined by minimum feasible leakage measurement for automatic testing.

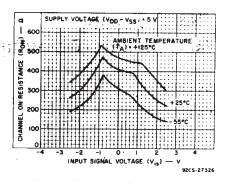


Fig. 3—Typical ON resistance vs. input signal voltage (all types).

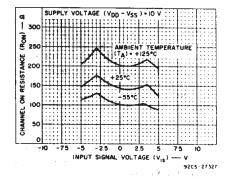


Fig. 4—Typical ON resistance vs. input signal voltage (all types).

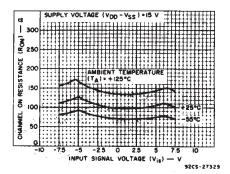


Fig. 5—Typical ON resistance vs. input signal voltage (all types).

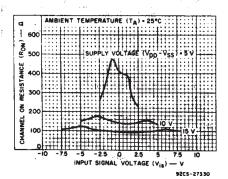
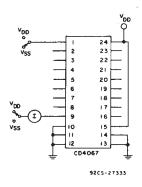


Fig. 6—Typical ON resistance vs. input signal voltage (all types).

#### **ELECTRICAL CHARACTERISTICS (Cont'd)**

CHARAC- TERISTIC	(	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							
	Vis	v <sub>ss</sub>	V <sub>DD</sub>	-55	-40	+85	+125		+25			
	(V)	(V)	(V)					Min.	Тур.	Max.		
Input Current, I <sub>IN</sub> Max.	V <sub>IN</sub> =	V <sub>IN</sub> = 0, 18 V			±0.1	±1	±1		±10 <sup>-5</sup>	±0.1	μΑ	
Propagation Delay Time: Address or		KΩ,C <sub>L</sub> = t <sub>r</sub> ,t <sub>f</sub> =20 ns										
Inhibit-to-		0	5	_				_	325	650		
Signal OUT (Channel		0	10		-	_	-	_	135	270	ns	
turning ON)		0	15	-	_	_	-		95	190	1	
Address or Inhibit-to-	R <sub>L</sub> =300 50 pF, 1	D Ω,C <sub>L</sub> = t <sub>r</sub> ,t <sub>f</sub> =20 ns										
Signal OUT		0	5	1 –	_	→ .	-	~-	220	440		
(Channel		0	10	-	_			_	90	180	ns	
turning OFF)		0	15	-		_	-	-	65	130	1	
Input Capaci- tance, C <sub>IN</sub>	Any Ad Inhibit	ddress or Input				_	-	5	7.5	рF		

#### **TEST CIRCUITS**



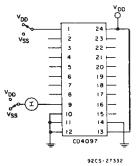


Fig. 7-OFF channel leakage current-any channel OFF.

### MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V <sub>DD</sub> )	
Voltages referenced to V <sub>SS</sub> Terminal)	
INPUT VOLTAGE RANGE, ALL INPUTS	0.5V to V <sub>DD</sub> +0.5V
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$	500mW
For T <sub>A</sub> = +100°C to +125°C	. Derate Linearity at 12mW/OC to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Ty	pes)100mW
OPERATING-TEMPERATURE RANGE (TA)	
STORAGE TEMPERATURE RANGE (Tstg)	65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 $\pm$ 1/32 inch (1.59 $\pm$ 0.79mm) from case for 10s max	+265°C

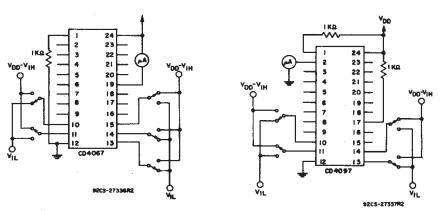


Fig. 8—Input voltage—measure  $\leq$  2  $\mu$ A on all OFF channels (e.g., channel 12).

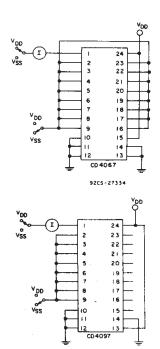
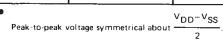


Fig. 9-OFF channel leakage current-all channels OFF.

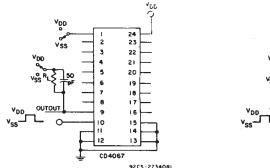
9205-27335

# ELECTRICAL CHARACTERISTICS (Cont'd)

			TE	ST COND	ITIONS	-	· · · · · ·		
CHARAC- TERISTIC	V <sub>is</sub> (V)	V <sub>DD</sub> (V)	R <sub>L</sub> (ΚΩ)				TYPICAL VALUES	UNITS	
Cutoff	5 <b>°</b>	10	1						
(-3-dB) Frequency		.,		V at Co	mmon OUT/IN	CD4067	14	ŀ	
Channel ON	$20 \log \frac{V_{os}}{V_{is}} = -3 dB$					CD4097	20	MHż	
(Sine Wave Input)				V <sub>os</sub> at An	y Channel	60	IVIHZ		
Total	2.	5					0.3		
Harmonic	3 <b>•</b>	10	10				0.2		
Distortion, THD	5 <sup>•</sup>	15					0.12	%	
	f <sub>is</sub> = 1	k'Hz sine	wave					, i	
-40-dB	5 <b>°</b>	10	1						
Feedthrough		V		V at Co	mmon OUT/IN	CD4067	20		
Frequency (All Channels	20 log	V <sub>os</sub>	10 dB	CD4097			12	MHz	
OFF		Vis		V <sub>os</sub> at An	y Channel	8			
	5 <b>°</b>	10	1						
Signal Cross-				Between A	Any 2 Channels		1		
talk (Fre-	20.100	$\frac{V_{os}}{V_{is}} = -2$	10 4B	Between	Measured on Co	ommon	10		
quency at -40 dB)	20 log	Vis	Ю ССВ	Sections CD4097 Only	Measured on Ai Channel	ny	18	MHz	
		10	10*						
Address-or-		), t <sub>r</sub> ,t <sub>f</sub> =2							
Inhibit-to- Signal		DD-VS		,			75	mV (Peak)	
Crosstalk	oquar	re Wave)						(reak)	



- Worst case.
- \* Both ends of channel.



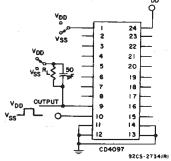


Fig. 11—Turn-on and turn-off propagation delay—address select input to signal output (e.g. measured on channel 0).

### TEST CIRCUITS (Cont'd)

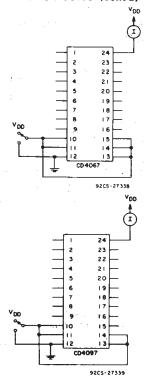
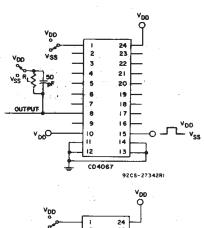


Fig. 10-Quiescent device current.



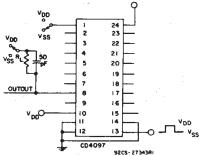
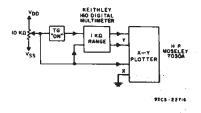
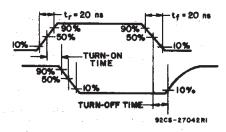


Fig. 12—Turn-on and turn-off propagation delay inhibit input to signal output (e.g. measured on channel 1).





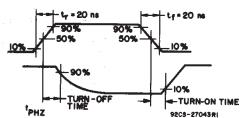


Fig. 13- Channel ON resistance measurement circuit.

Fig. 14— Propagation de/ay waveform channel being turned ON ( $R_L$  = 10 K  $\Omega$ ,  $C_L$  = 50 pF).

Fig. 15 — Propagation delay waveform, channel being turned OFF ( $R_L$  = 300  $\Omega$ ,  $C_L$  = 50 pF).

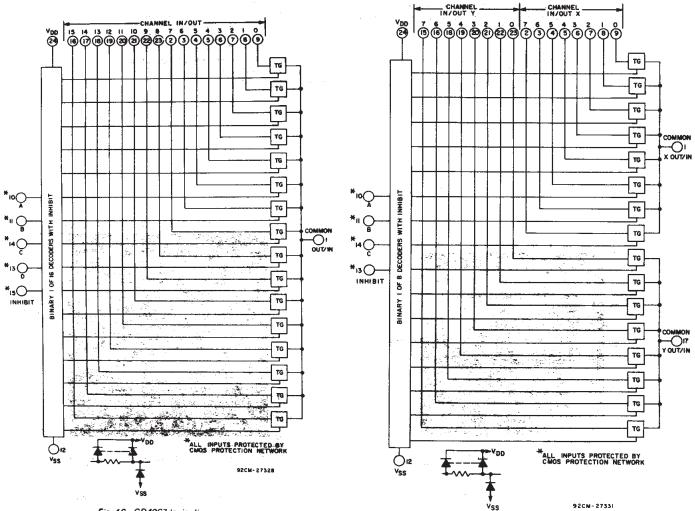


Fig. 16-CD4067 logic diagram.

Fig. 17-CD4097 logic diagram.

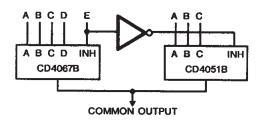


Fig. 18-24-to-1 MUX Addressing

#### SPECIAL CONSIDERATIONS

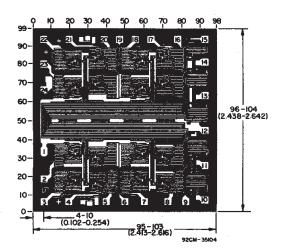
In applications where separate power sources are used to drive V<sub>DD</sub> and the signal inputs, the V<sub>DD</sub> current capability should exceed V<sub>DD</sub>/R<sub>L</sub> (R<sub>L</sub>=effective external load). This provision avoids permanent current flow or clamp action on the V<sub>DD</sub> supply when power is applied or removed from the CD4067B or CD4097B.

When switching from one address to another, some of the ON periods of the channels of the multiplexers will overlap momentarily, which may be objectionable in certain applications. Also when a channel is turned on or off by an address input, there is a momentary conductive path from the channel to VSS, which will dump some charge from any capacitor connected to the input or output of the channel. The inhibit input turning on a channel will similarly dump some charge to VSS.

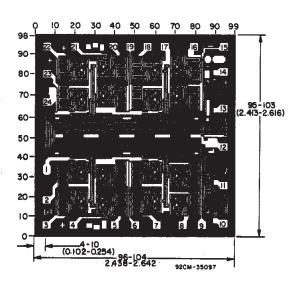
The amount of charge dumped is mostly a function of the signal level above VSS. Typically, at  $V_{DD}$ - $V_{SS}$ =10 V, a 100-pF

capacitor connected to the input or output of the channel will lose 3-4% of its voltage at the moment the channel turns on or off. This loss of voltage is essentially independent of the address or inhibit signal transition time, if the transition time is less than 1-2 µs. When the inhibit signal turns a channel off, there is no charge dumping to VSS. Rather, there is a slight rise in the channel voltage level (65 mV typ.) due to capacitive coupling from inhibit input to channel input or output. Address inputs also couple some voltage steps onto the channel signal levels.

In certain applications, the external load-resistor current may include both VDD and signal-line components. To avoid drawing VDD current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 volt (calculated from RON values shown in ELECTRICAL CHARACTERISTICS CHART). No VDD current will flow through RL if the switch current flows into terminal 1 on the CD4067B, terminals 1 and 17 on the CD4097B.



Dimensions and pad layout for CD4067BH.



Dimensions and pad layout for CD40978H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils  $(10^{-3} \text{ inch})$ .



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## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD4067BE	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4067BEE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4067BF	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type
CD4067BF3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type
CD4067BM	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BM96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BM96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BM96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BMG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BPW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BPWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4067BPWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BE	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4097BEE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4097BF	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type
CD4097BM	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BM96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BM96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BM96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BMG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BPW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BPWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BPWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BPWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



### PACKAGE OPTION ADDENDUM

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Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins I	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD4097BPWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4097BPWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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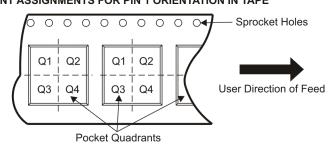
# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4067BM96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD4097BM96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD4097BPWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 29-Jul-2009

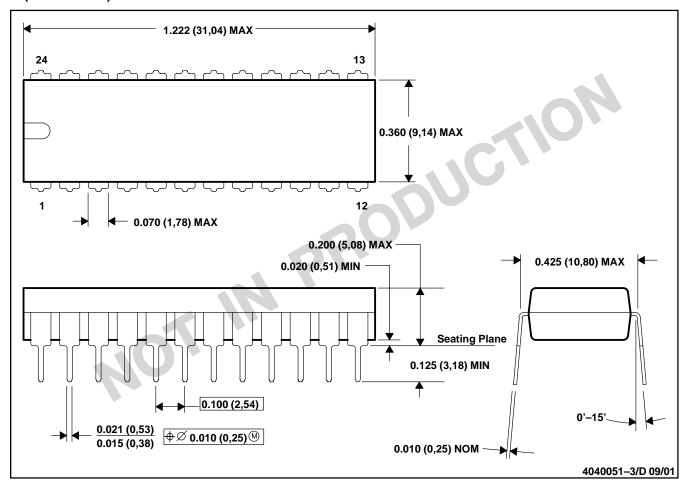


\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4067BM96	SOIC	DW	24	2000	346.0	346.0	41.0
CD4097BM96	SOIC	DW	24	2000	346.0	346.0	41.0
CD4097BPWR	TSSOP	PW	24	2000	346.0	346.0	33.0

## N (R-PDIP-T24)

## PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-010

## PW (R-PDSO-G\*\*)

## 14 PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

4040084/C 10/97

## J (R-GDIP-T\*\*)

## 24 PINS SHOWN

## **CERAMIC DUAL-IN-LINE PACKAGE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



# DW (R-PDSO-G24)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



## N (R-PDIP-T\*\*)

#### PLASTIC DUAL-IN-LINE PACKAGE

#### 24 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-011
- D. Falls within JEDEC MS-015 (32 pin only)



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